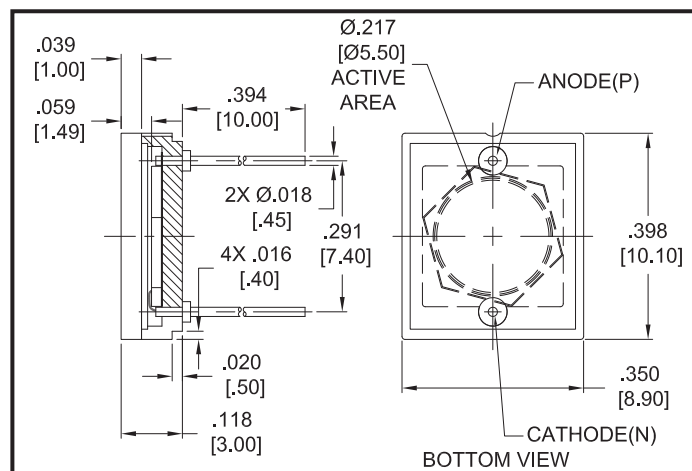


**FEATURES**

- Circular active area
- Ideal for 190-400 nm detection
- 100% internal QE
- UV quartz window epoxy bonded in place

Dimensions are in inch [metric] units.

ELECTRO-OPTICAL CHARACTERISTICS AT 25°C

PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Active Area	Ø 5.5 mm		24		mm ²
Responsivity, $\mathcal{R}$	@ 254 nm	0.105	0.115	0.125	A/W
Shunt Resistance	$V_F = \pm 10$ mV	50	100		Mohm
Reverse Breakdown Voltage, V_R	$I_R = 1$ μ A	10	50		Volts
Capacitance, C	$V_R = 0$ V		2.5	4	nF
Rise Time	$V_R = 0$ V			4	μ sec

THERMAL PARAMETERS

STORAGE AND OPERATING TEMPERATURE RANGE	
Storage Temperature Range	-20° TO 80°C
Maximum Junction Temperature	80°C
Lead Soldering Temperature ¹	240°C

¹0.0625" from case for 10 seconds.

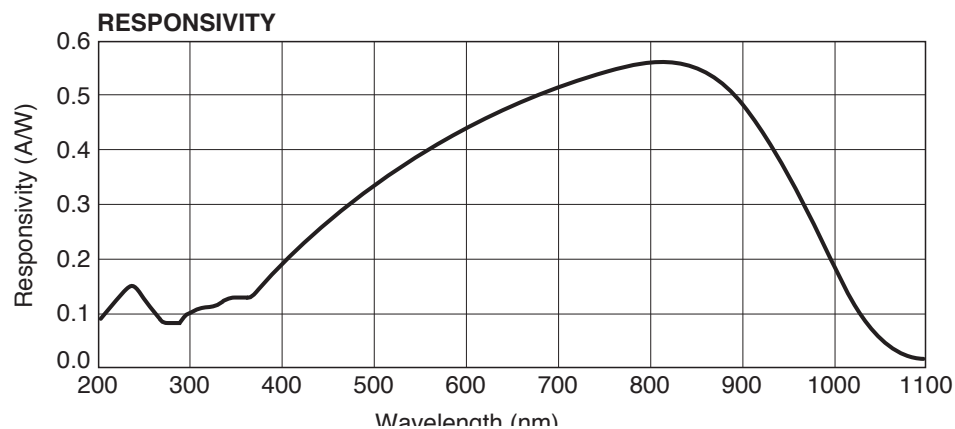


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